

Amendments to the Claims:

1. (Original) An aluminum nitride sintered body having a maximum length of 320 mm or more, a thickness of more than 0 mm and 2 mm or less, a warpage of 0 $\mu\text{m}/\text{mm}$ or more and less than 1 $\mu\text{m}/\text{mm}$, and a local waviness height of 0 μm or more and 50 μm or less after a sintering step is finished.

Claims 2-22 (Cancelled by Article 34)

23. (Currently Amended) An aluminum nitride sintered body having a maximum length of 320 mm or more, a thickness of more than 0 mm and 2 mm or less, a warpage of 0 $\mu\text{m}/\text{mm}$ or more and less than 1 $\mu\text{m}/\text{mm}$, and a local waviness height of 0 μm or more and 50 μm or less, wherein the ~~aluminum-nitride~~ sintered body is formed by polishing one side of the sintered body according to claim 1 with a polishing allowance of 10 μm or less.

24. (Currently Amended) The aluminum nitride sintered body according to claim 1 or 23, wherein the sintered body has a thickness of less than 1 mm.

25. (Currently Amended) The aluminum nitride sintered body according to claim 1, 23 or 24, wherein the sintered body has the a thermal conductivity of 85 $\text{W}/\text{m}\cdot\text{K}$ or more and 105 $\text{W}/\text{m}\cdot\text{K}$ or less and is used for a heater substrate.

26. (Currently Amended) A metallized substrate comprising: ~~a plate-shaped substrate made of the aluminum nitride sintered body according to any one of claims 1 and 23 to 25, and an electrically conductive metallized layer formed on at least a part of the substrate.~~

a plate-shaped substrate made of an aluminum nitride sintered body having a maximum length of 320 mm or more, a thickness of more than 0 mm and 2 mm or less, a warpage of 0 $\mu\text{m}/\text{mm}$ or more and less than 1 $\mu\text{m}/\text{mm}$, and a local waviness height of 0 μm or more and 50 μm after a sintering step is finished; and

an electrically conductive metallized layer that is formed on at least a part of the substrate.

27. (Currently Amended) ~~A metallized substrate having a warpage of 0 $\mu\text{m}/\text{mm}$ or more and 5 $\mu\text{m}/\text{mm}$ or less, comprising a substrate including an aluminum nitride sintered body having a maximum length of 320 mm or more, a thickness of more than 0 mm and 2 mm or less, and a local waviness height of 0 μm or more and 50 μm or less, and an electrically conductive metallized layer formed on at least a part of a surface of the substrate.~~

The metallized substrate according to claim 26, comprising:

a substrate including an aluminum nitride sintered body having a maximum length of 320 mm or more, a thickness of more than 0 mm and 2 mm or less, and a local waviness height of 0 μm or more and 50 μm or less;

an electrically conductive metallized layer formed on at least a part of a surface of the substrate, wherein the metallized substrate has a warpage of 0 $\mu\text{m}/\text{mm}$ or more and 5 $\mu\text{m}/\text{mm}$ or less.

28. (Currently Amended) A heater comprising: ~~the metallized substrate according to claim 26 or 27; an electrode part arranged on the metallized layer and connected to the metallized layer; and an insulating layer arranged on the metallized layer.~~

a metallized substrate comprising a plate-shaped substrate made of an aluminum nitride sintered body having a maximum length of 320 mm or more, a thickness of more than 0 mm and 2 mm or less, a warpage of 0 $\mu\text{m}/\text{mm}$ or more and less than 1 $\mu\text{m}/\text{mm}$, and a local waviness height of 0 μm or more and 50 μm or less after a sintering step is finished, an electrically conductive metallized layer formed on at least a part of the substrate;

an electrode part arranged on the metallized layer and connected to the metallized layer;
and

an insulating layer arranged on the metallized layer.

29. (Original) A method for producing an aluminum nitride sintered body, comprising the steps of:

preparing a raw material containing a binder and a major material of aluminum nitride;

forming a sheet-shaped molded body using the raw material;

natural drying of the molded body for 10 hours or more;

removing the binder from the molded body after the drying step; and

sintering the molded body free of the binder, wherein the sintering step is performed by arranging the molded body in a space surrounded by a jig comprising boron nitride as a major component, wherein the ratio of the volume of the molded body to the volume of the space is in the range of 20% to 60%.

30. (Original) The method for producing an aluminum nitride sintered body according to claim 29, wherein the sintering step is performed by arranging the molded body one by one in the space surrounded by the jig comprising boron nitride as the major component.

31. (Currently Amended) The method of producing an aluminum nitride sintered body according to claim 29 ~~or 30~~, wherein the jig has a depressed portion on the top surface of a flat plate-shaped base to place the molded body, and the sintering step is performed in a state wherein a plurality of said jigs are piled up to form a jig pile.

32. (Currently Amended) The method for producing an aluminum nitride sintered body according to claim ~~31~~ 29, wherein the sintering step is performed in a state wherein the jig pile is placed inside of a case made of a metal material.

33. (Original) A jig used in a sintering step to produce an aluminum nitride sintered body having a maximum length of 320 mm or more and a thickness of more than 0 mm and 2 mm or less, comprising a flat plate-shaped base containing boron nitride and having a depressed portion formed on the surface of the base to place the molded body, wherein dimensions of the depressed

portion are determined such that the ratio of the volume of the molded body to the volume of the depressed portion being in the range of 20% to 60%.